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"SCHOOL ON POLYMER PHYSICS"

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"CONDUCTING POLYMERS"

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These late (preliminary) lecture notes, intended only for distribution to participants.
Please no extra copies are available in Room 231.

CONDUCTING POLYMERS

-2-

1. INTRODUCTION

SURVEY OF ELECTRICAL CONDUCTION IN ORGANIC MATERIALS
CHARGE TRANSFER COMPLEXES
 $(SN)_x$
 $(CH)_x$, DOPING
OTHER CONJUGATED POLYMERS
PHTHALOCYANINE DERIVATIVES
"BECHGAARD" SALTS

2. SYNTHESIS

$(CH)_x$ FILM SYNTHESIS, ZIEGLER-NATTA CATALYSTS
OTHER $(CH)_x$ CATALYSTS
EFFECT OF SOME VARIABLES
"DURHAM/FEAST" $(CH)_x$ USING PRECURSORS
REPRESENTATIVE OTHER SYNTHESSES"
POLYPHENYLENE VINYLENE
MITTIG REACTION
PRECURSOR ROUTE

3. DOPING

P- AND N-DOPANTS, UNIFORMITY
COMPENSATION
ANISOTROPY
ELECTROCHEMICAL DOPING

4. MORPHOLOGY

NASCENT $(CH)_x$ MORPHOLOGY
CRYSTALLINITY
OTHER MORPHOLOGIES
STRUCTURE DETERMINATIONS
OTHER POLYMERS

5. PHYSICAL PROPERTIES

ELECTRICAL CONDUCTIVITY
MAGNETIC SUSCEPTIBILITY
TEMPERATURE DEPENDENCY
BAND GAP
ELECTRICAL ANISOTROPY
ESR PROPERTIES
CIS-TRANS ISOMERIZATION OF $(CH)_x$
THERMOELECTRIC POWER

6. CONDUCTION MECHANISMS

BAND STRUCTURE THEORY: SOLITONS, POLARONS
PERCOLATION MODELS

7. APPLICATIONS

AS CONDUCTORS
BATTERIES
DEVICES

SELECTED BIBLIOGRAPHY

SYNTHETIC METALS (JOURNAL) FROM 1979, ELSEVIER

R. BAUGHMAN ET AL. CHEM. REV., 82, 209 (1982)

CONDUCTING POLYMERS, T. SKOTHEIM, ED., M. DEKKER, N.Y., 1984

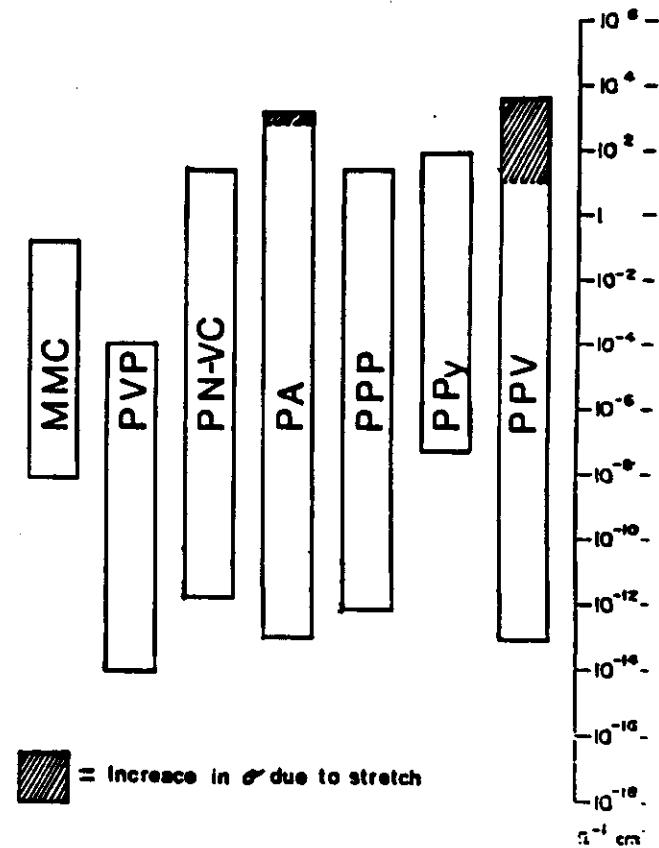
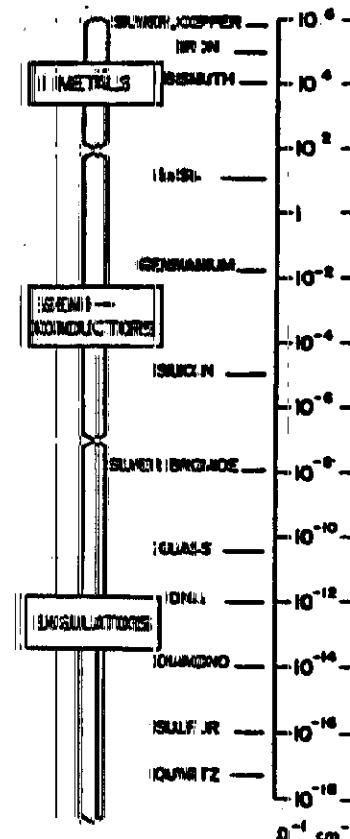
POLYACETYLENE, J. C. W. CHIEN, ACADEMIC PRESS, N.Y., 1984.

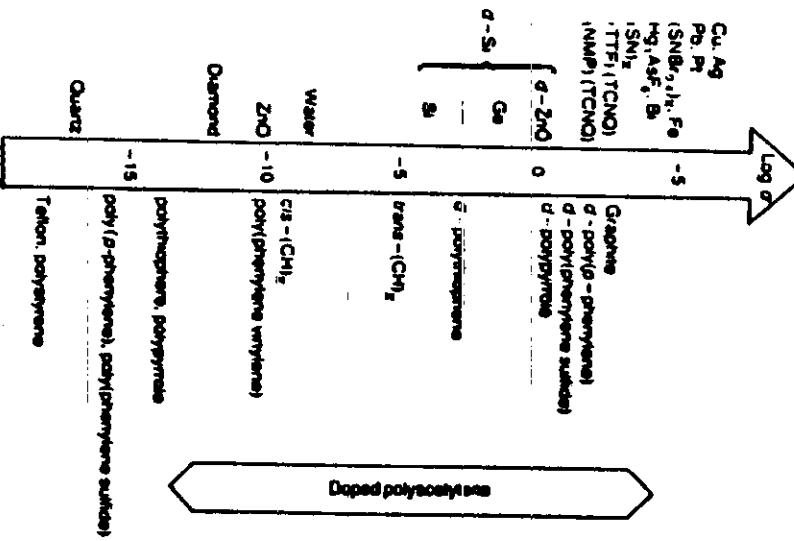
A. G. MACDIARMID, ANN. REV. PHYS. CHEM., 33, 443 (1982)

K. SEGER, ANGEW. MAKROM. CHEMIE., 109, 227 (1982) (DOKTORANDEN-AUSSTELLUNG)

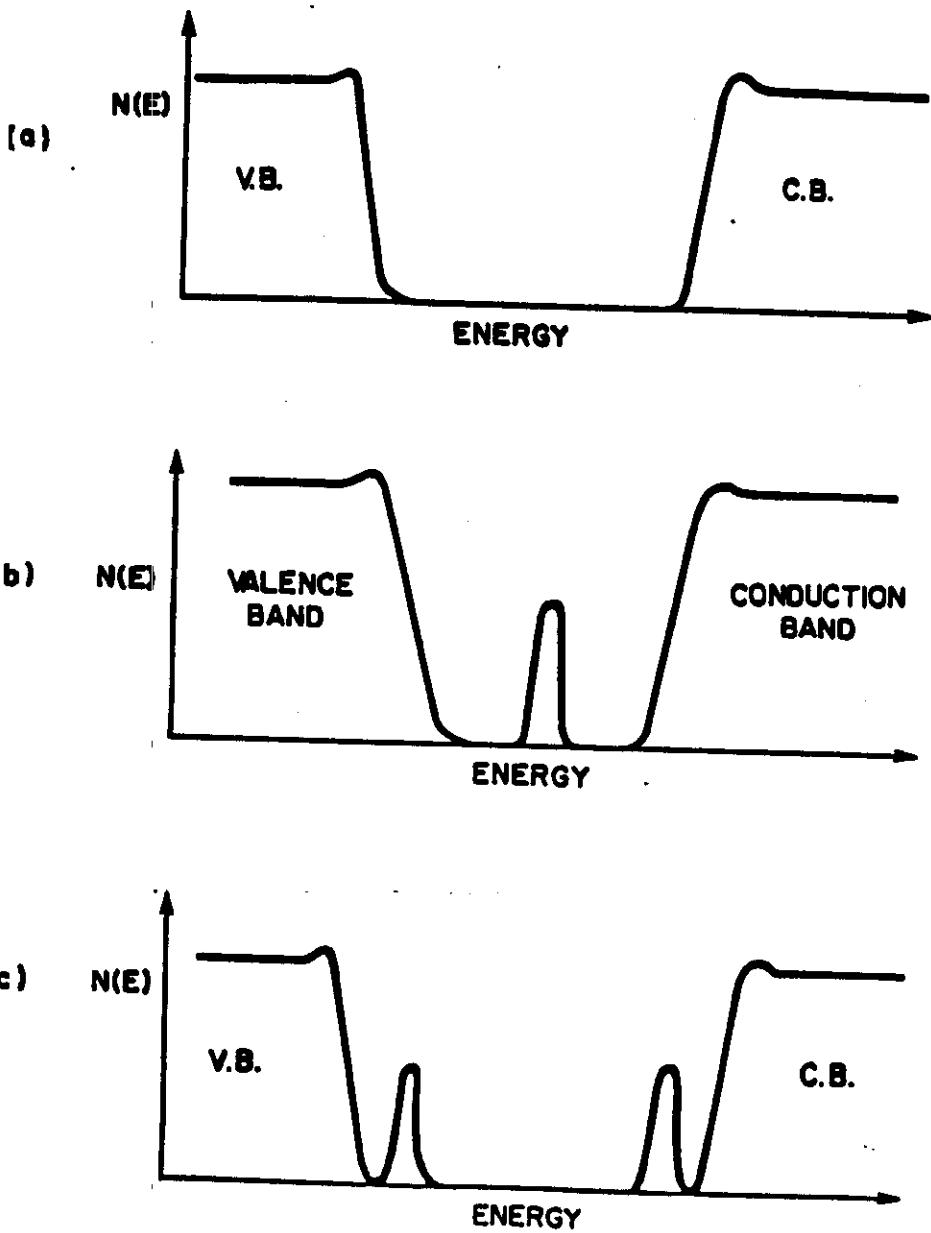
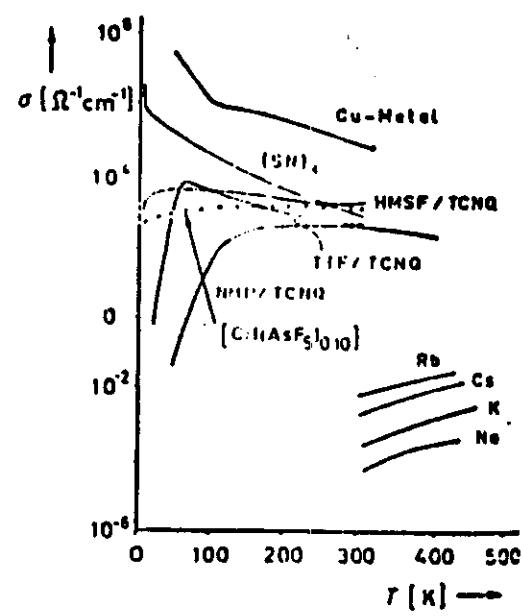
G. WEGNER, ANG. CHEM. INT. ED., 20, 361 (1981)

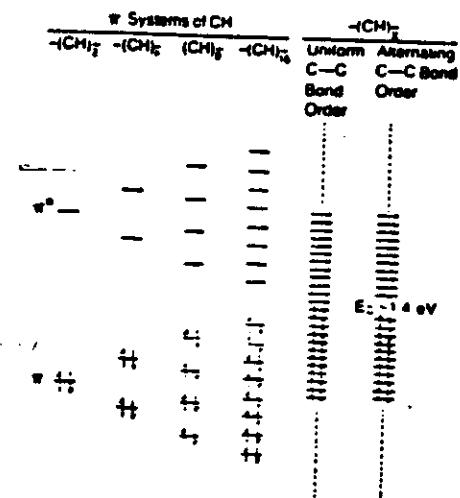
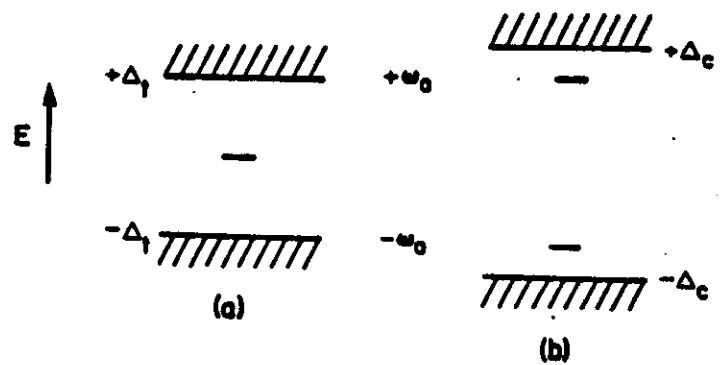
W. HAYES, CONTEMP. PHYS., 26, 421 (1985)





Note: α indicates doped material.



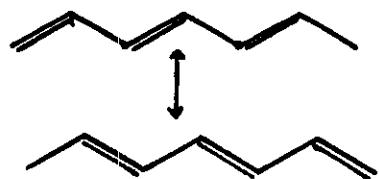


Diagrammatic representation of the energy levels of π MOs with increasing size of the molecule for $[CH]_x$.

CONJUGATED POLYMERS

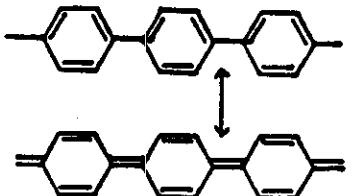
SYNTHESSES & FORM

Poly (acetylene)



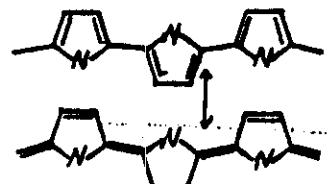
vapor/film

Poly (o-phenylene)



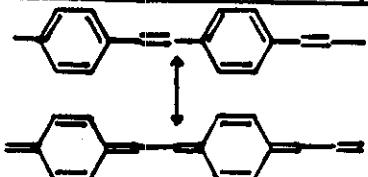
solution/powder

Poly (pyrrole)

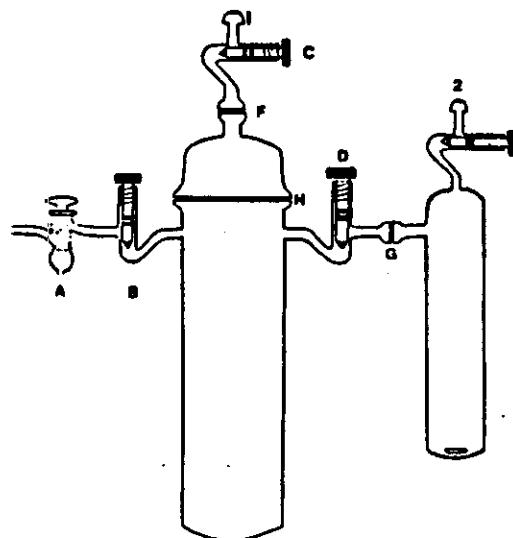


e-diem/film

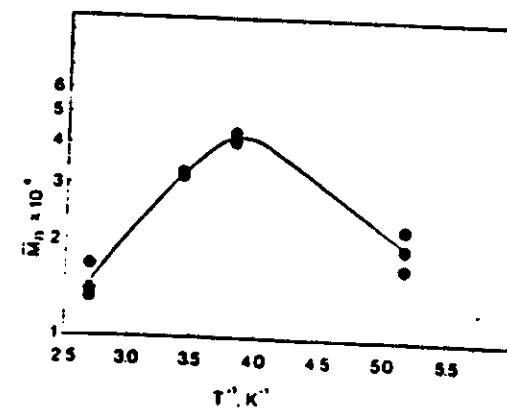
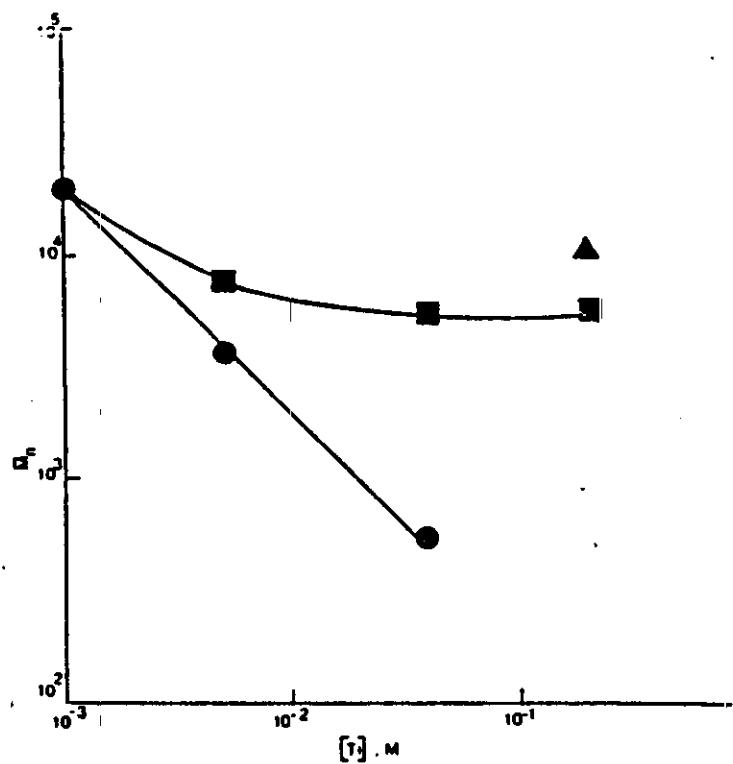
Poly (o-phenylene vinylene)

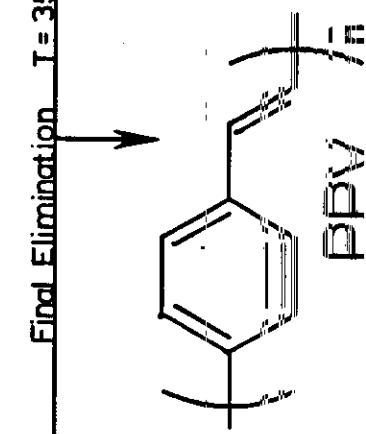
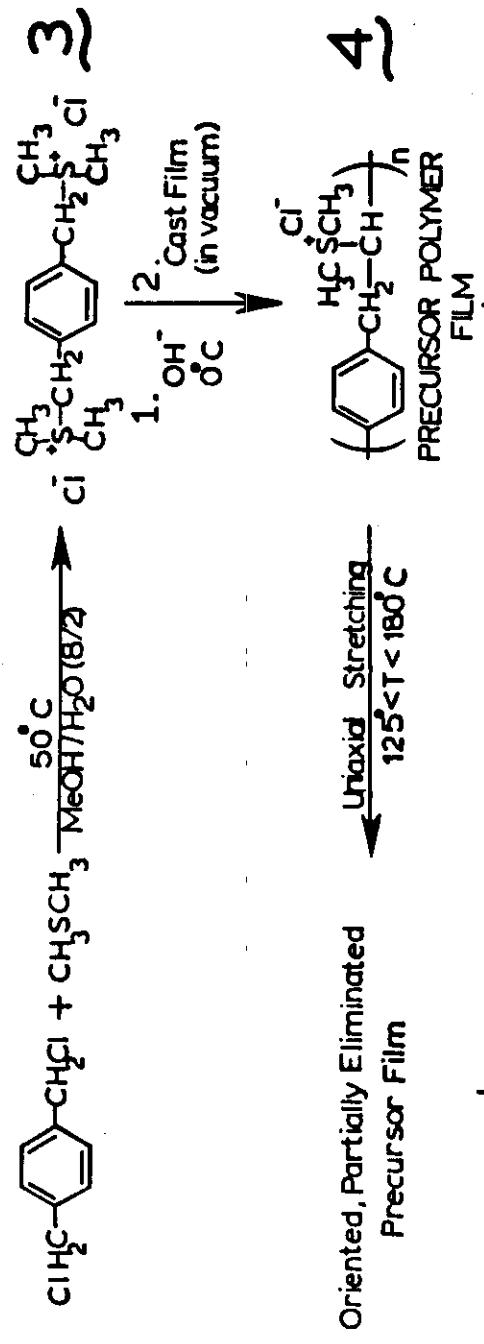


solution/powder
precursor/film



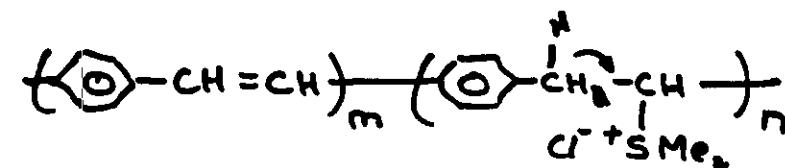
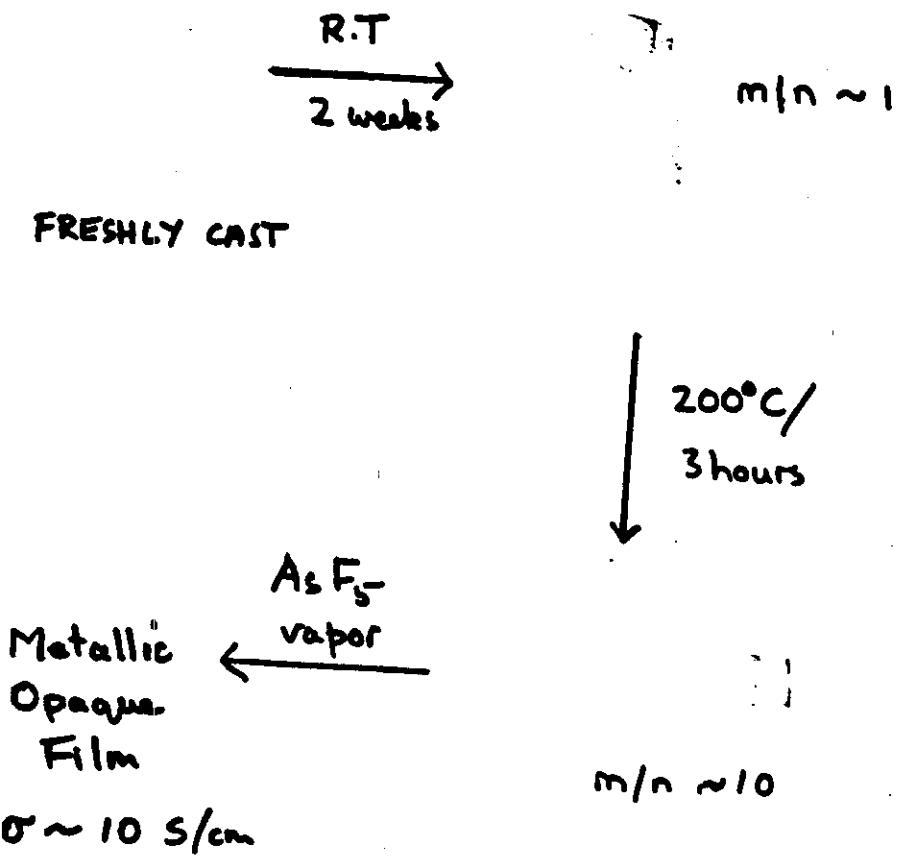
Apparatus for the synthesis of (CH)_x films.

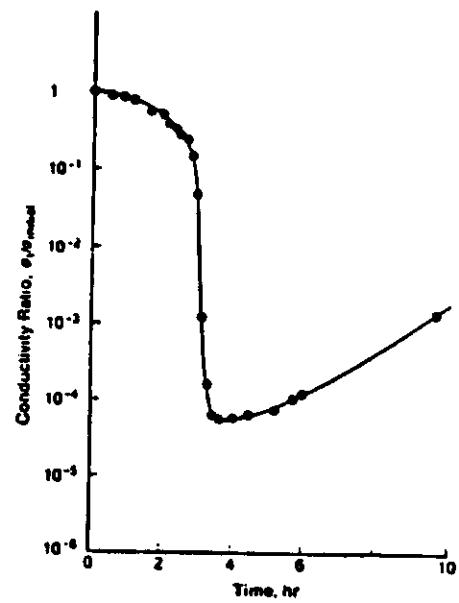
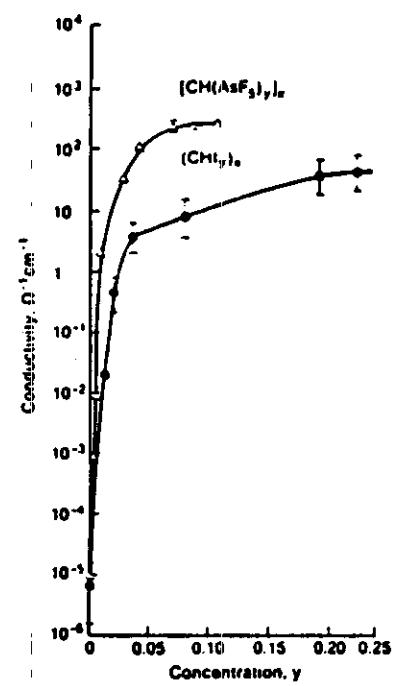


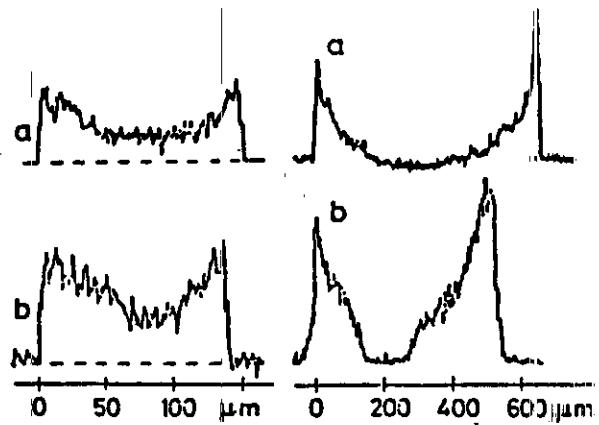


SCHEME 1: Synthesis and Processing of PPV

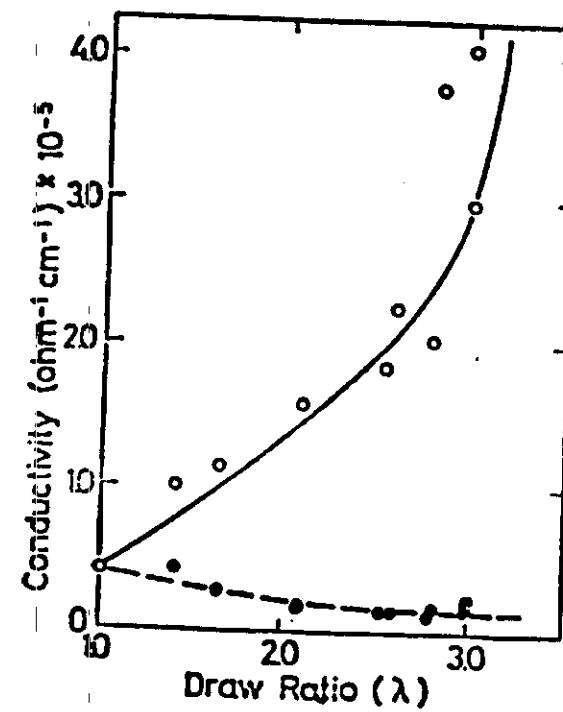
SHOW AND TELL







Iodine energy dispersive X-ray analysis profiles of iodine-doped polyacetylene of thickness 150 μm (left) and 600 μm (right).



Electrical conductivity of stretch-aligned trans-(CH)_x films as a function of the draw ratio.

AsF₅ DOPING

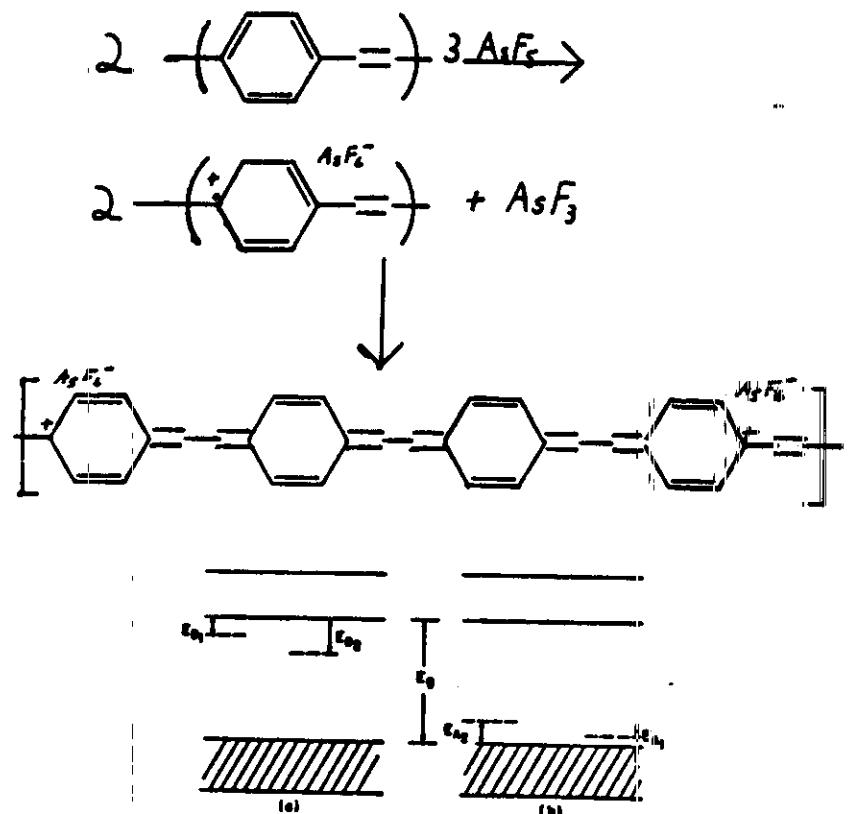
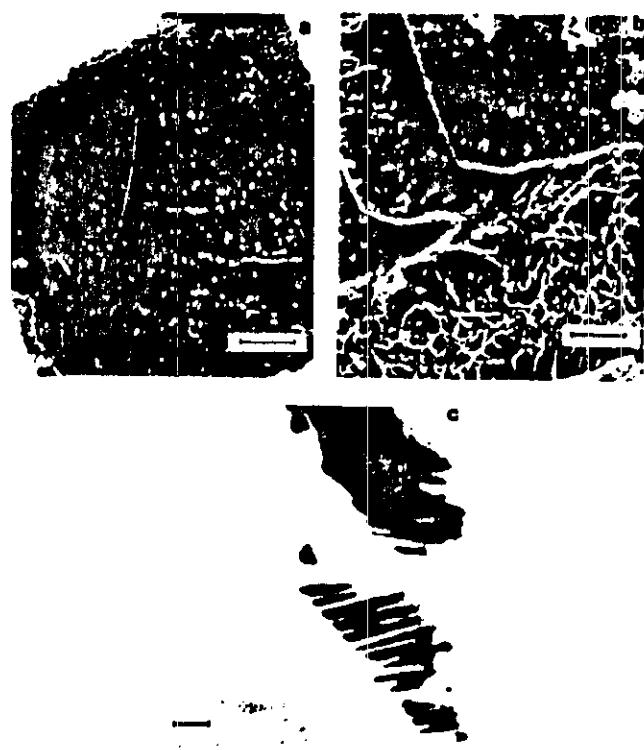


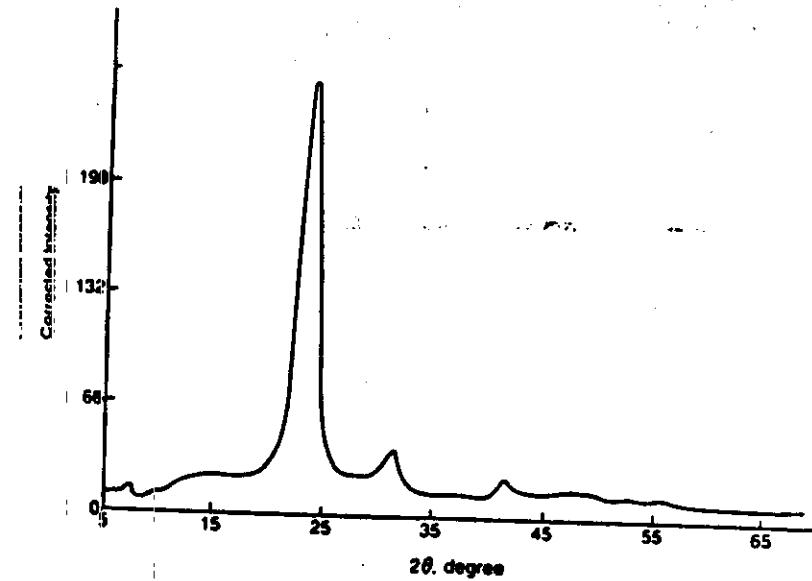
FIG. 8. (a) An energy band diagram for an n-type semiconductor containing two donor centers with different activation energies, E_{D_1} and E_{D_2} ; (b) a p-type semiconductor with two different acceptor centers.



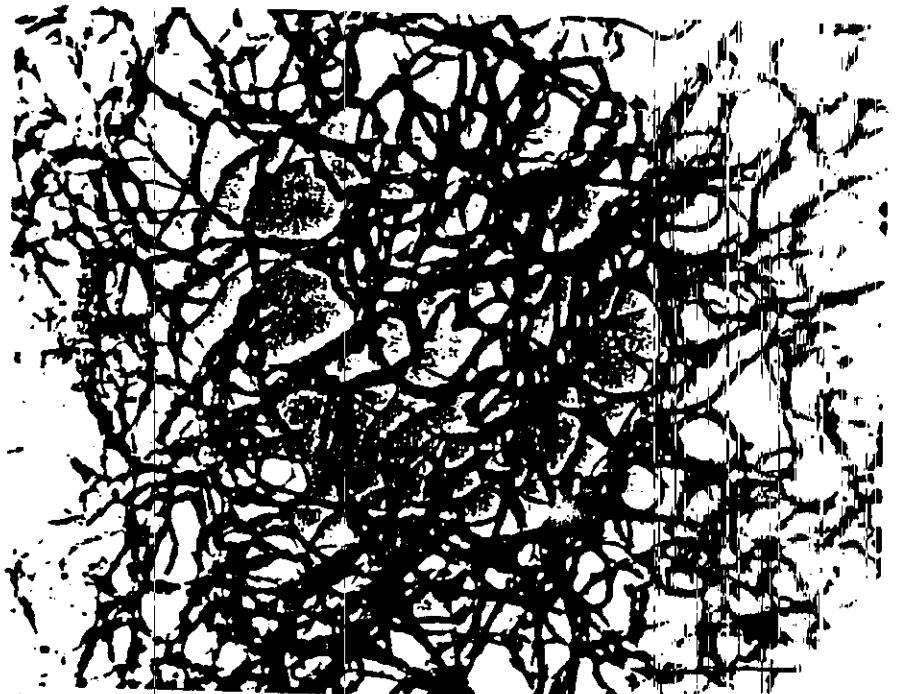
Electron micrograph of an ultrathin *trans*-polyacetylene film. (a) as prepared.
(b) after exposure of 30 min to air at room temperature.



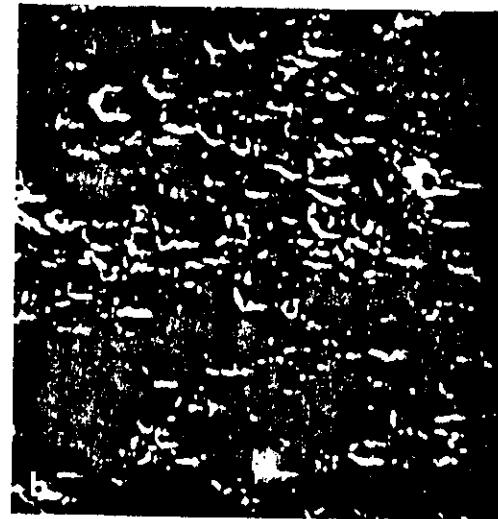
SEM micrographs of thin polyacetylene films polymerized directly onto a gold grid at 760 torr of acetylene for ~ 1 min., dried and sputter coated with 3 nm of gold; (a) $\times 500$, scale bar = 10 μm ; (b) $\times 9000$, scale bar = 1 μm ; (c) $\times 60,000$, scale bar = 0.1 μm .



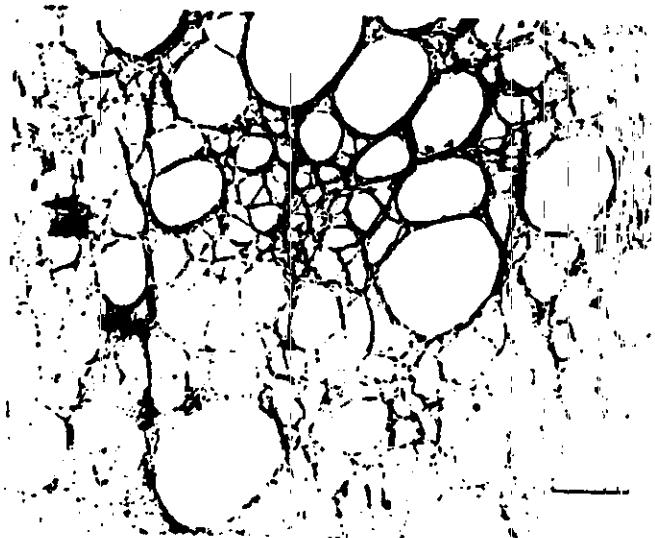
Wide-angle X-ray diffraction patterns for *cis*-polyacetylene film.



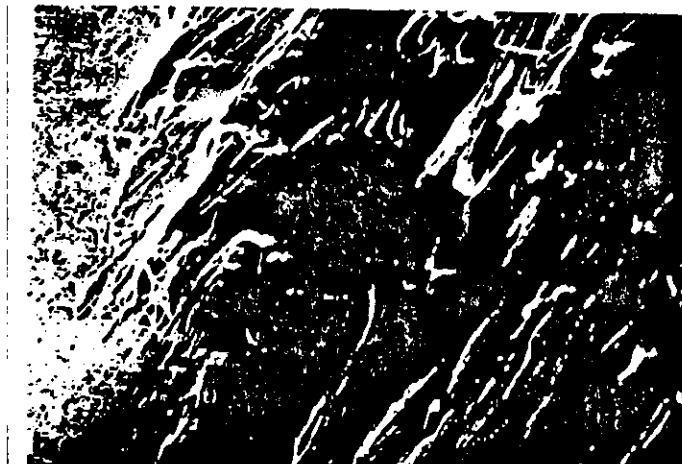
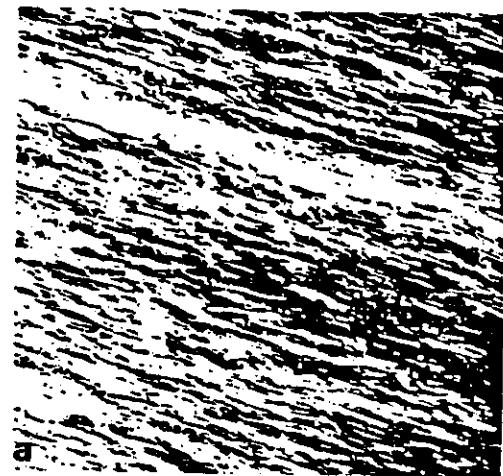
Electron micrograph of nascent polyacetylene polymerized directly onto the EM grid with the diisopropyl catalyst. Magnification 50,000X.



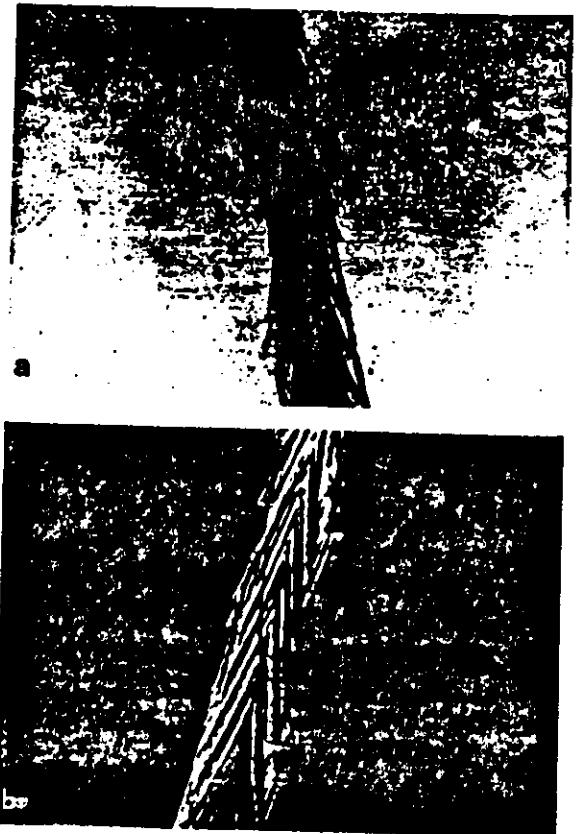
Scanning electron micrographs of free-standing polyacetylene film: (a) dull face away from the reactor surface; (b) shiny face toward the reactor surface. Magnification 50,000X.



Electron micrograph of nascent *cis*-polyacetylene. Marker is 500 nm.

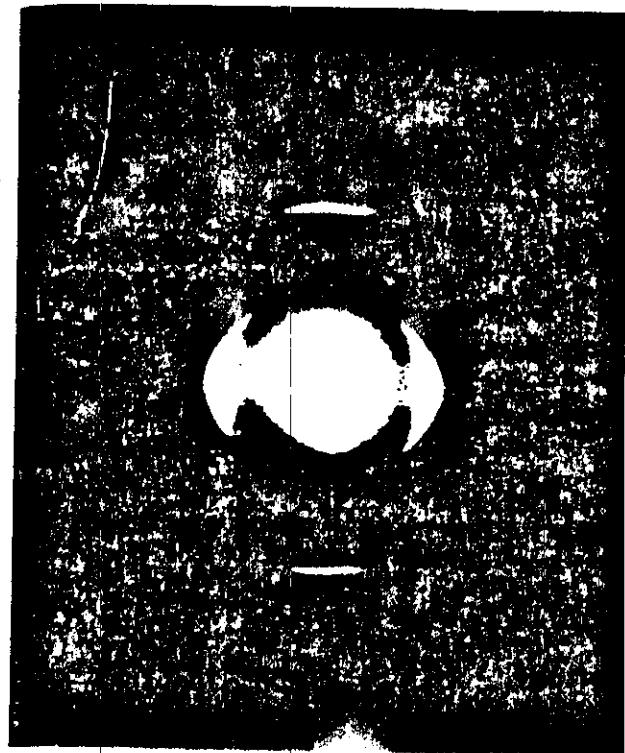


Coextruded polyacetylene film: (a) smooth surface, magnification 5000 \times ; (b) fractured area, magnification 8000 \times .

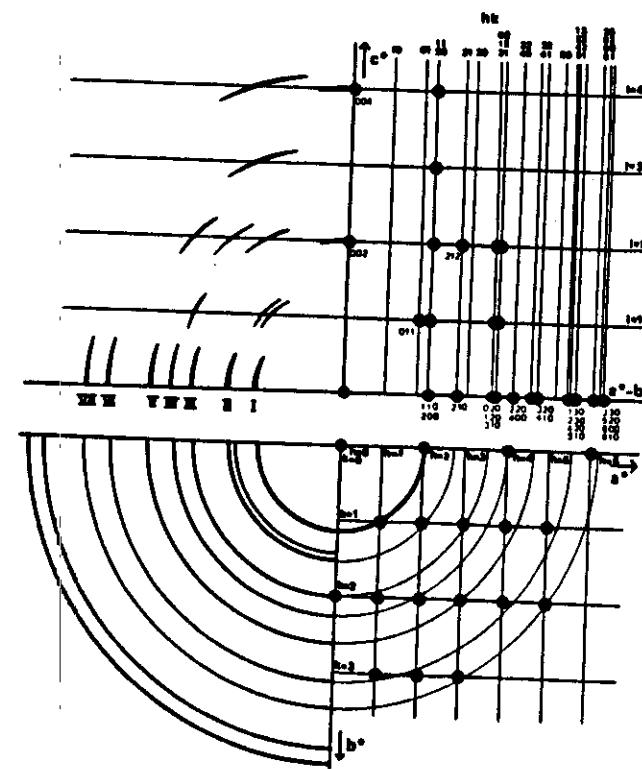


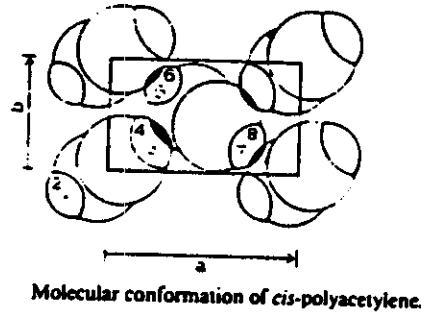
Polymerization of acetylene under a hydrodynamic flow field: (a) polymers grown from ends of a magnetic stirring bar, 1.35 X magnification; (b) pieces broken off from the stirrer.

3.3 Crystal Structure of *cis*-Polyacetylene

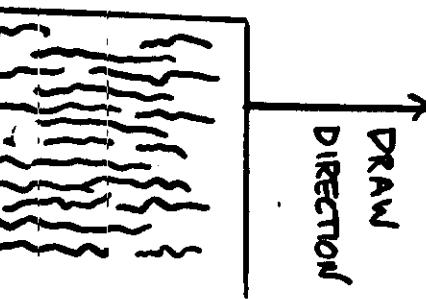


Electron diffraction patterns of aligned fibrils of nascent *cis*-polyacetylene.





Molecular conformation of *cis*-polyacetylene.



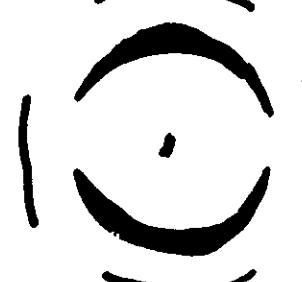
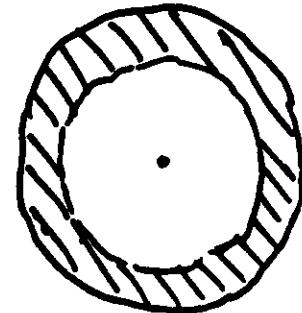
$$\frac{d}{d_0} = 14.5$$

$$\frac{d}{d_0} = 10$$

$$\frac{d}{d_0} = 1.9$$

$$\frac{d}{d_0} = 1.1$$

$$\frac{d}{d_0} = 1$$



SUMMARY OF STRUCTURES

Using Me_2S as "plasticizer"

Fibers; Oriented Films

- Drawn at $150-200^\circ\text{C}$; air or argon
- Fibrillation at $\epsilon/\epsilon_0 > 10$
- Alternative: solid state co-extrusion
- Or: drawn from gel

Foams

- 600% volume increase ie $\rho \sim 0.2$
- Flexible; open-celled.

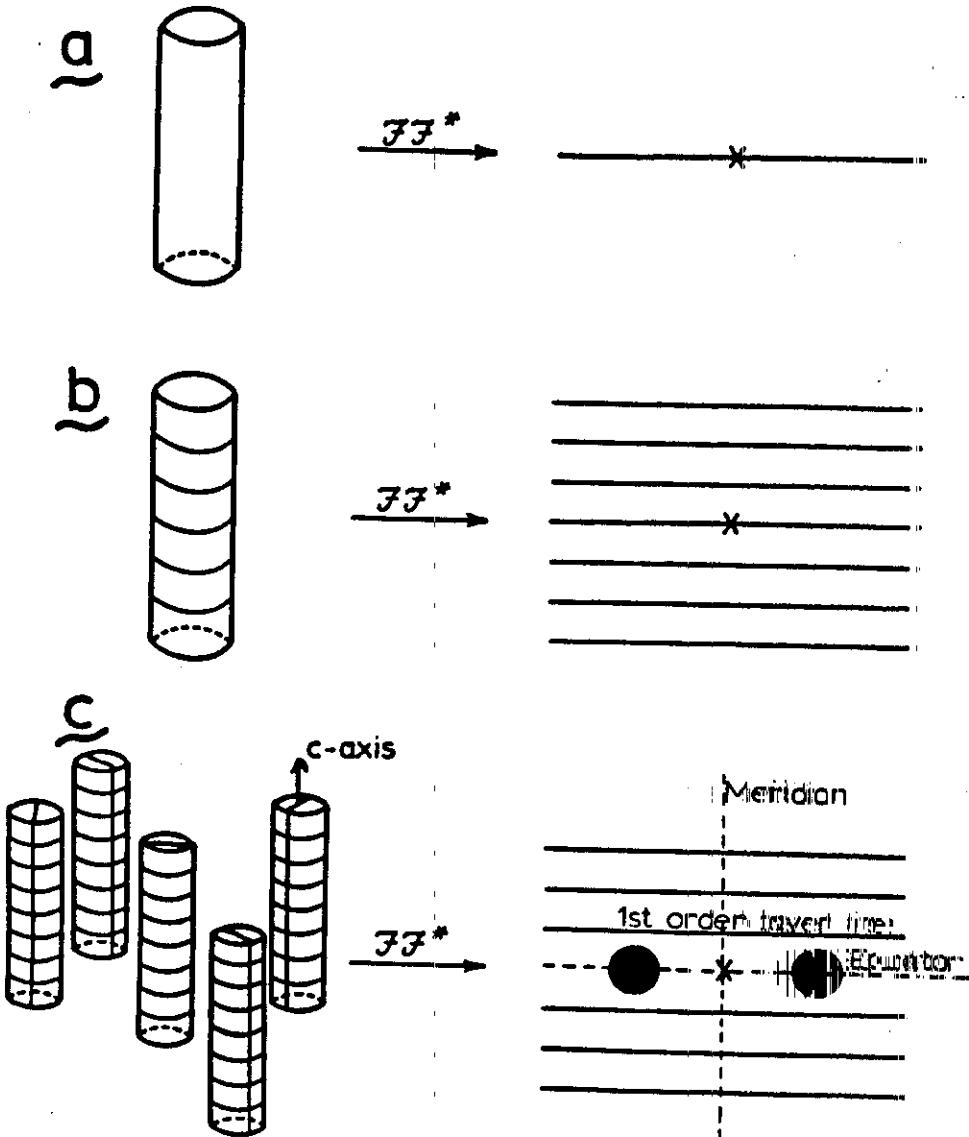
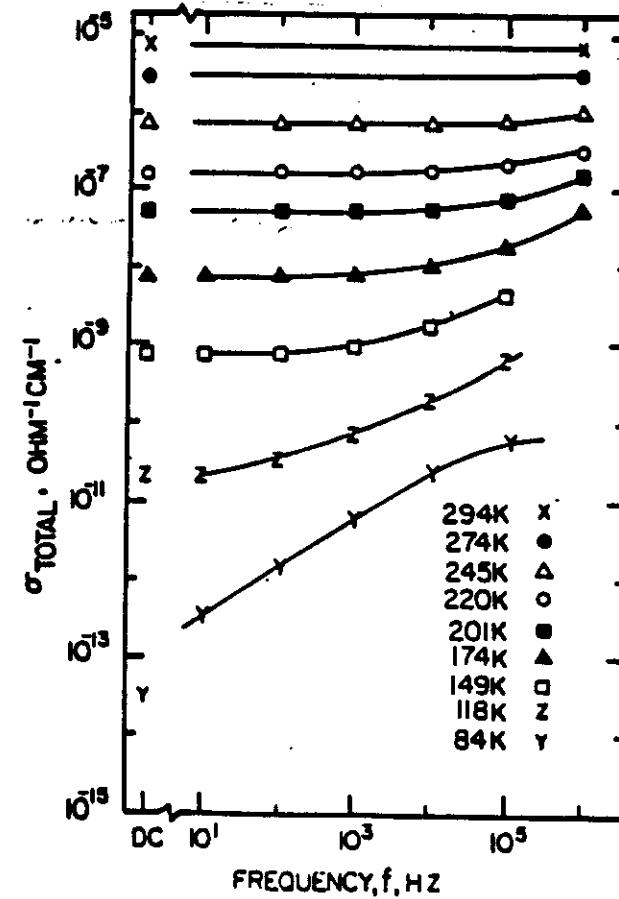
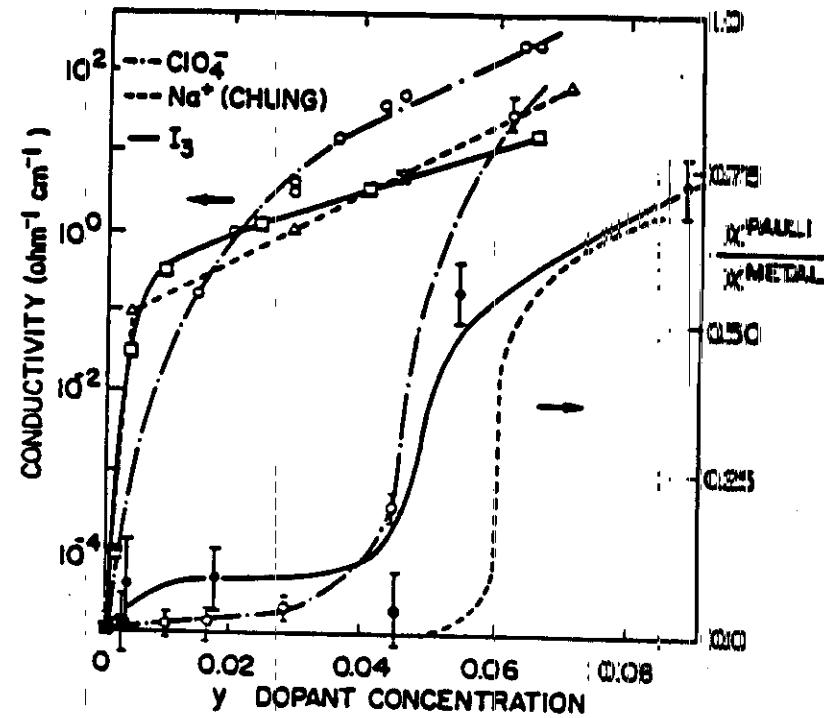
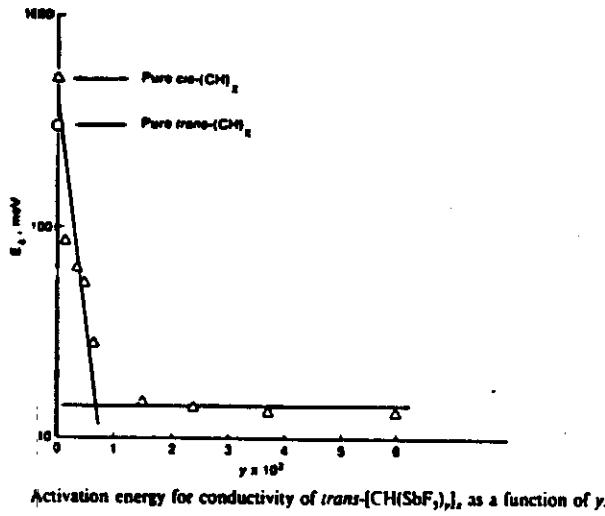
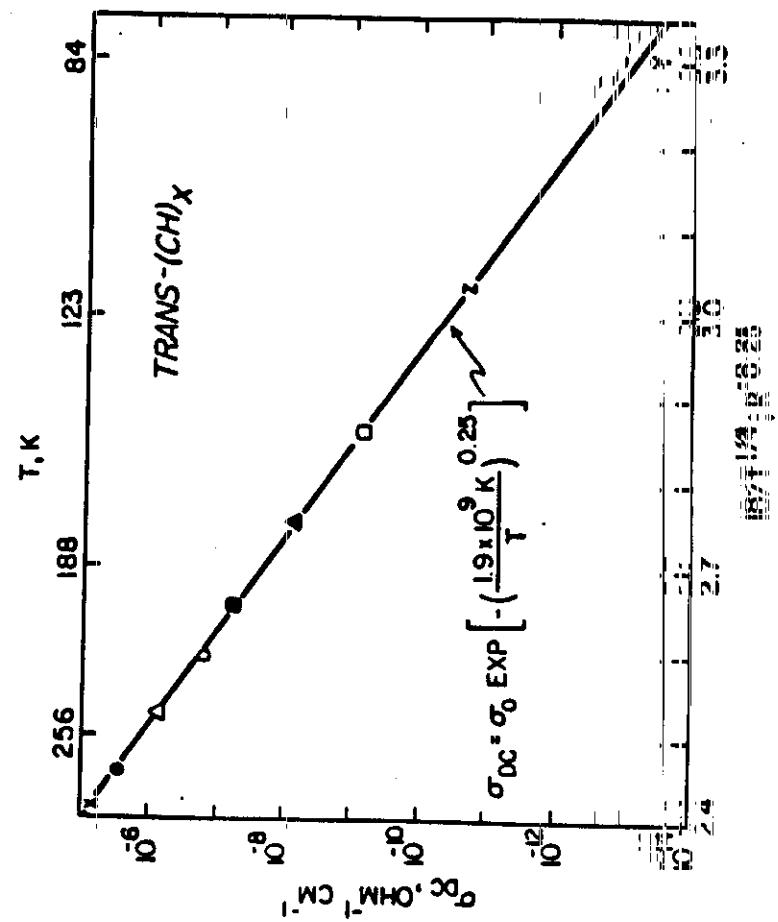
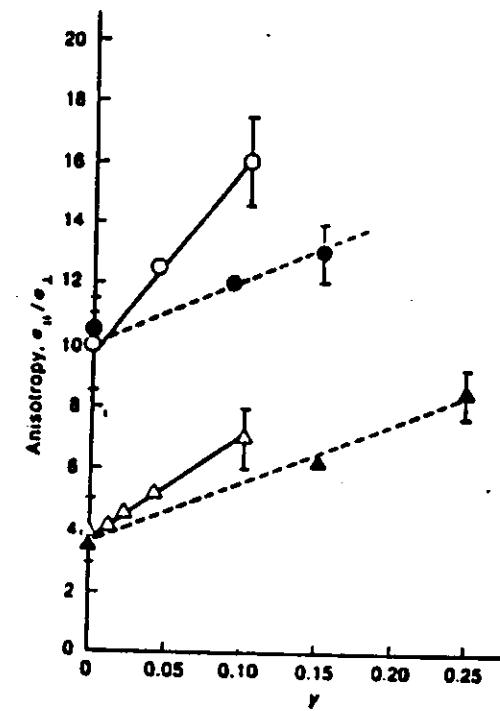
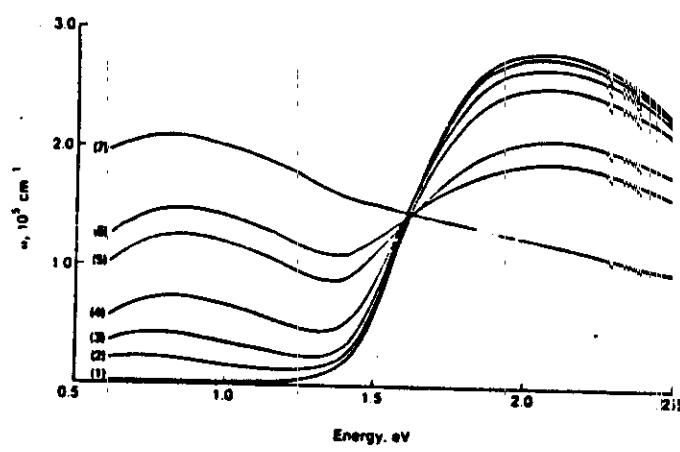
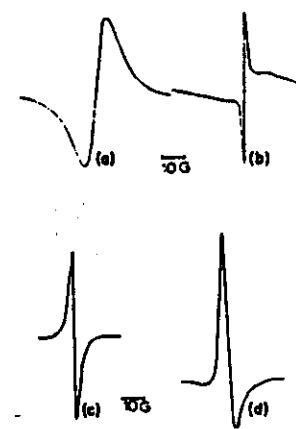
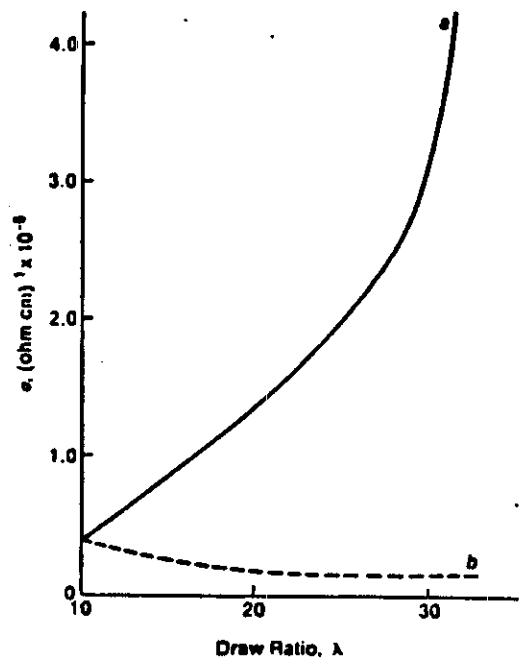


Figure 2

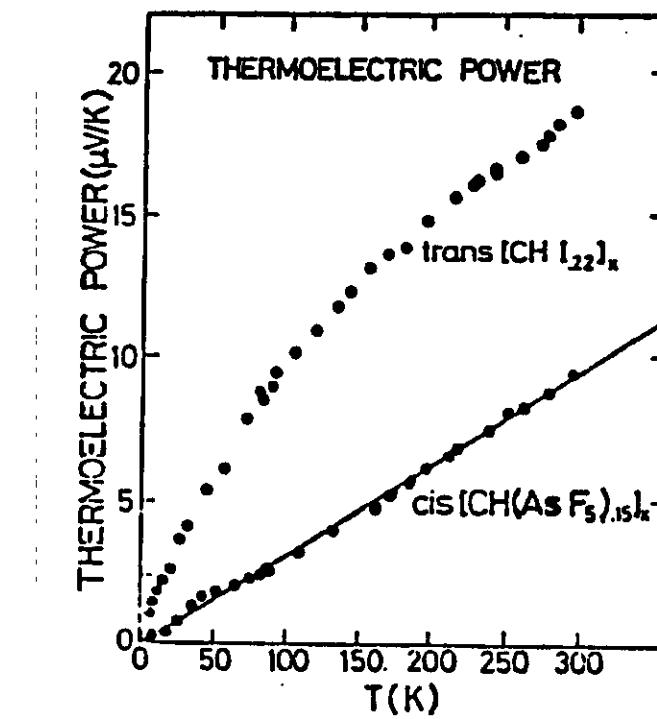
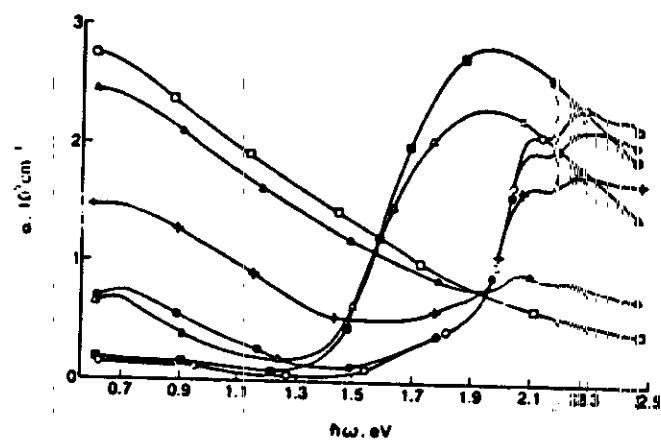




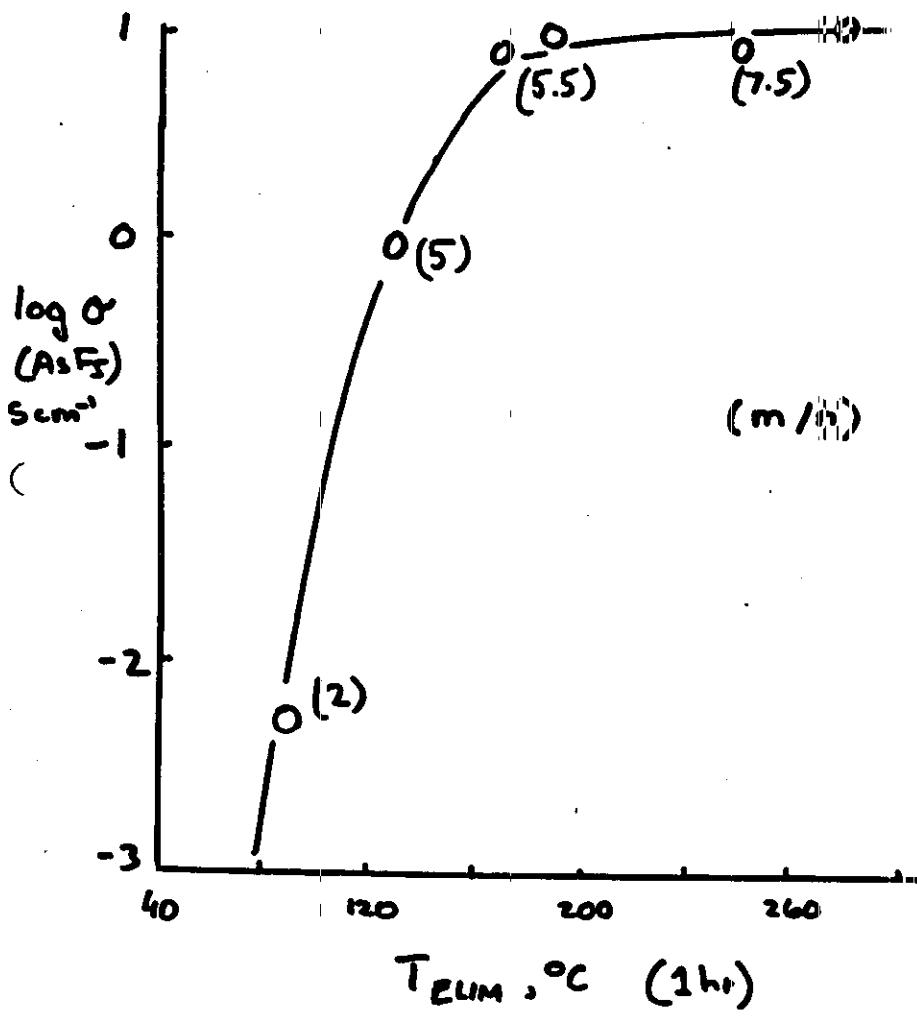




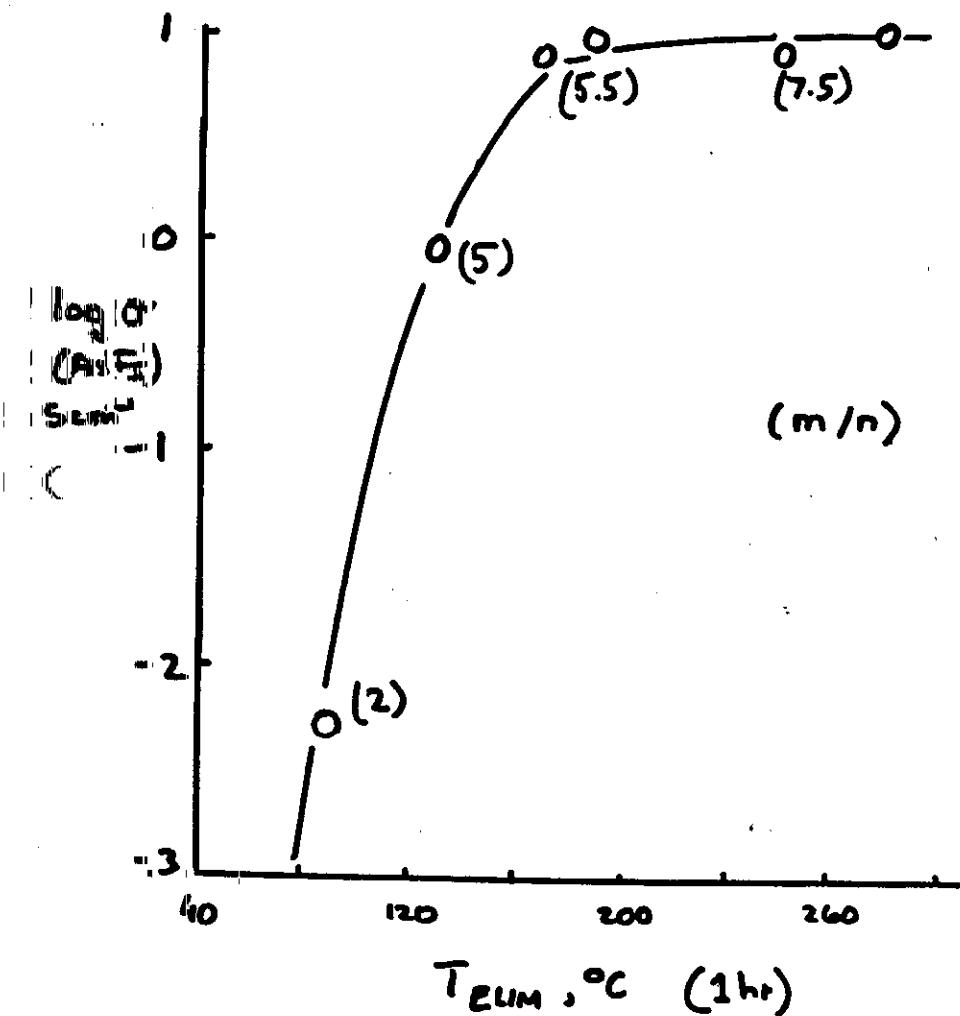
Red



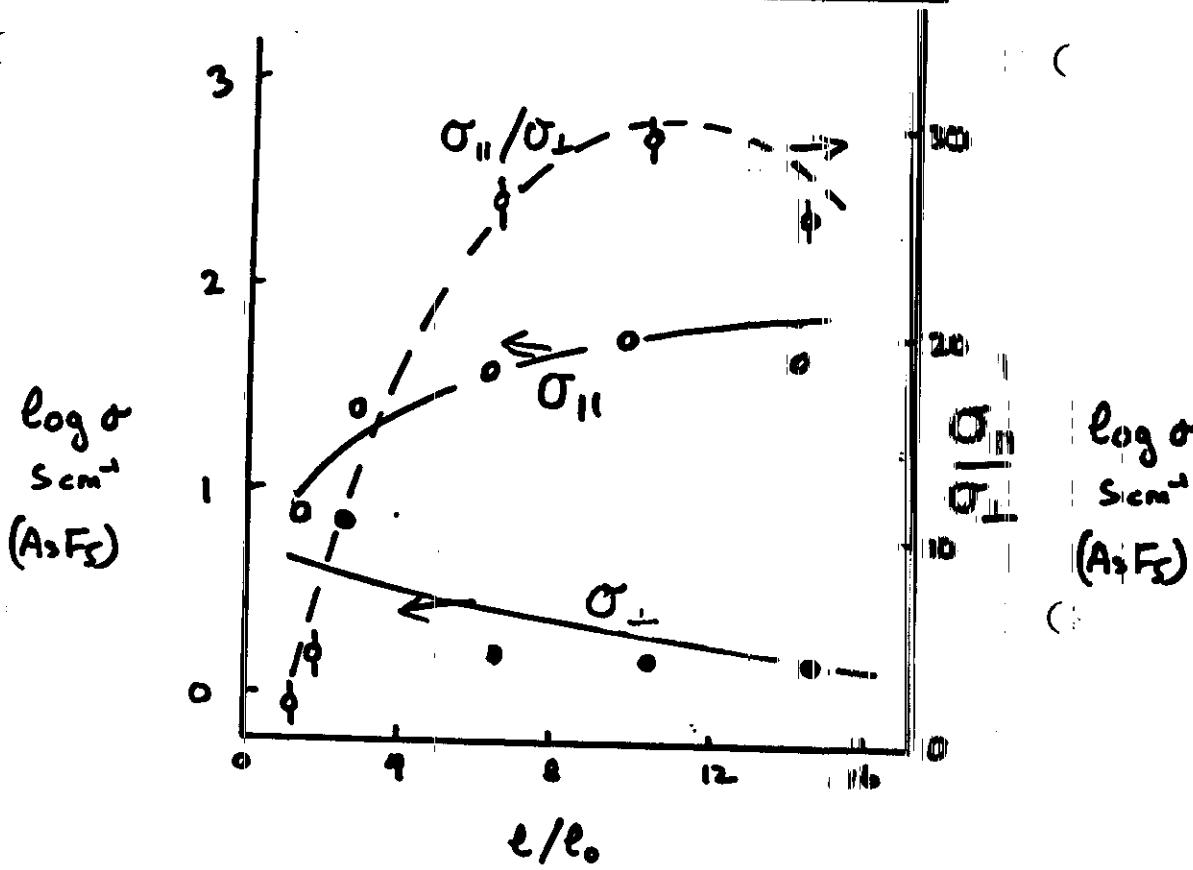
CONDUCTIVITY (UNORIENTED)



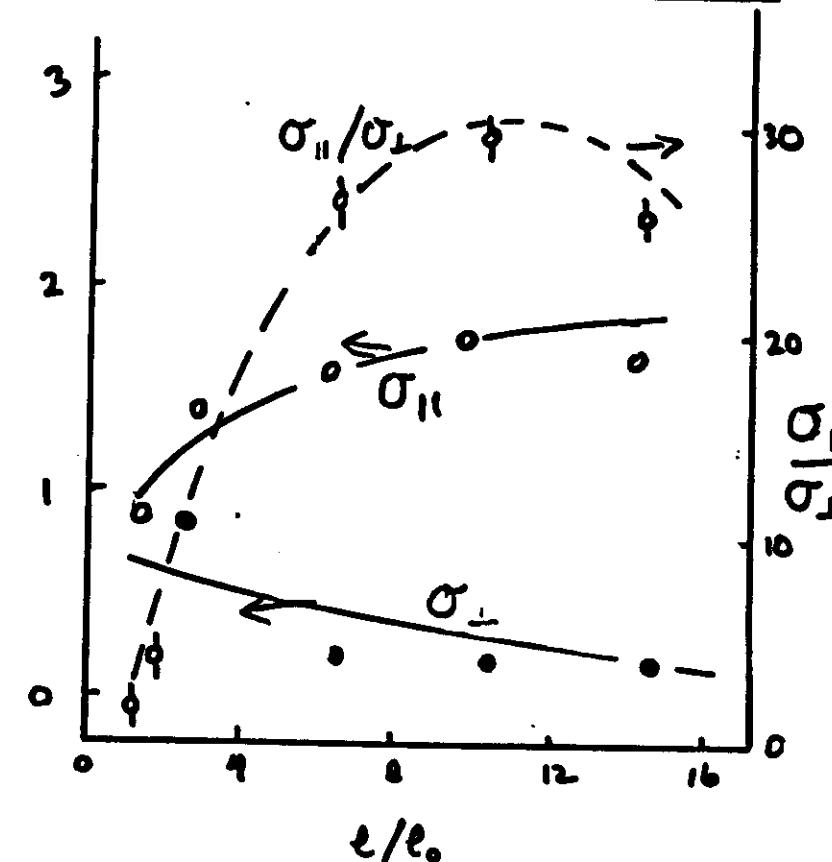
CONDUCTIVITY (UNORIENTED)



CONDUCTIVITY AND ORIENTATION

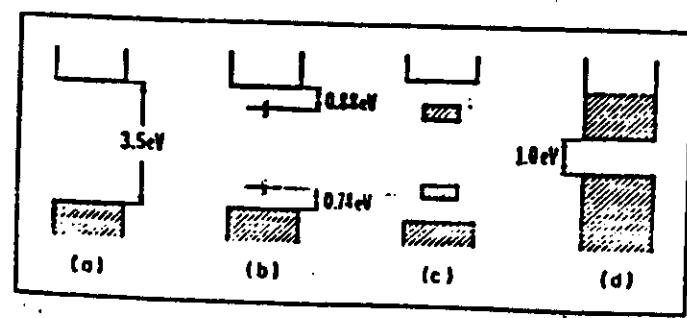
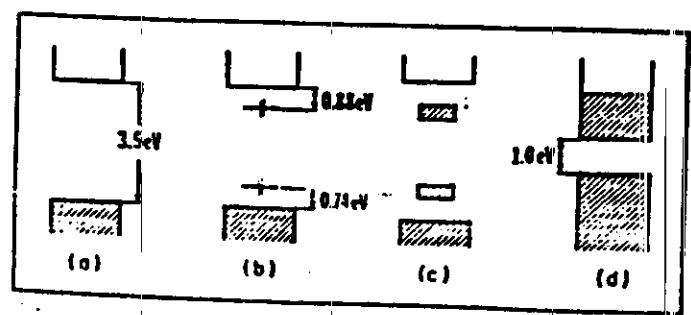


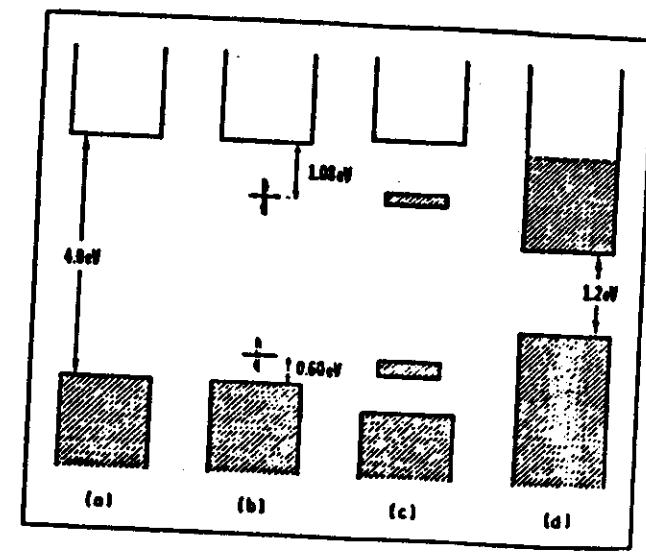
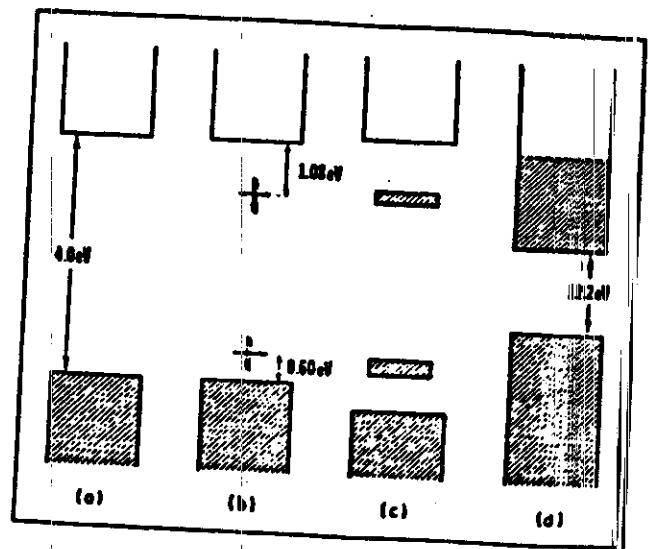
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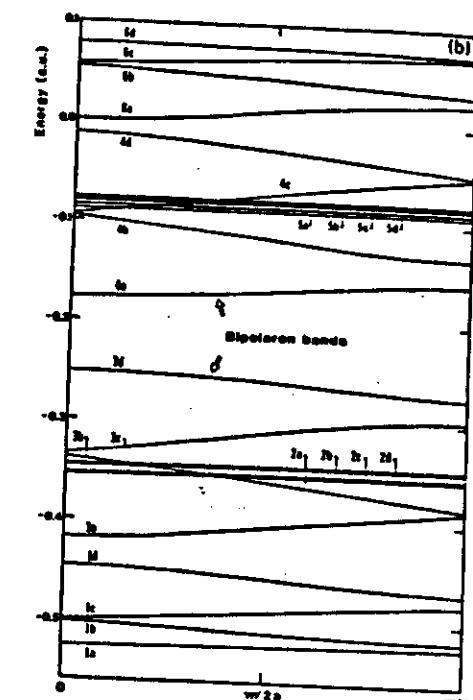
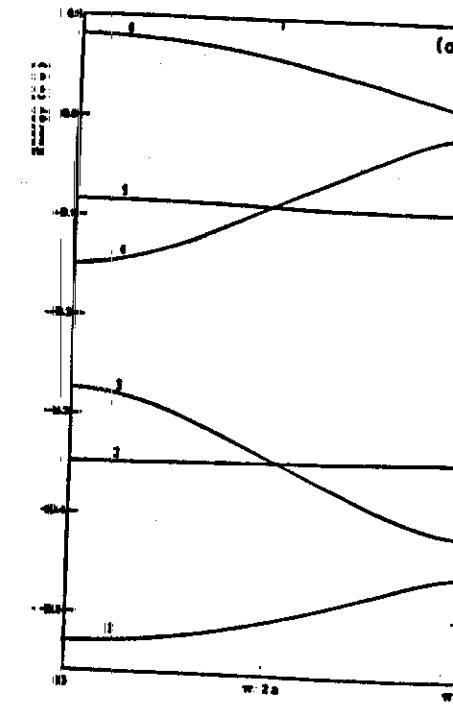
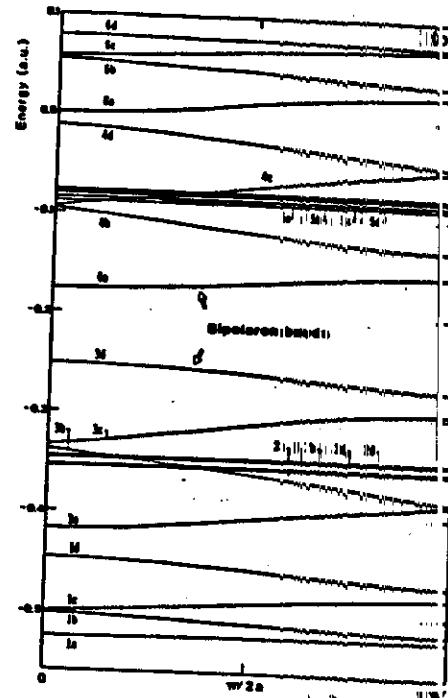
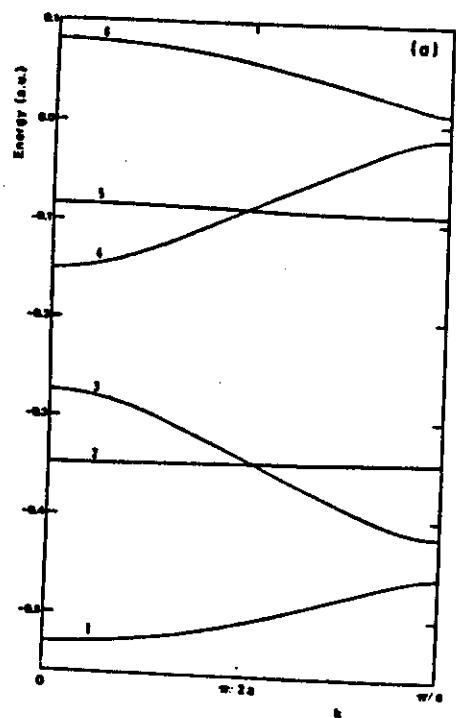


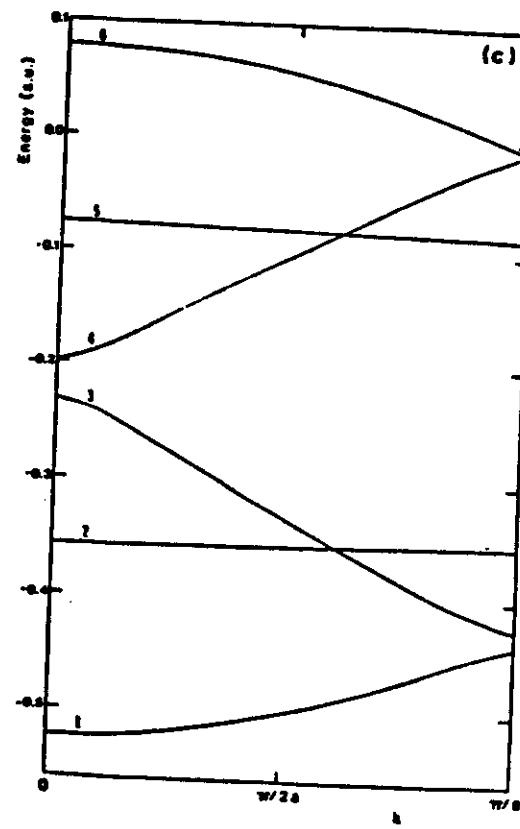
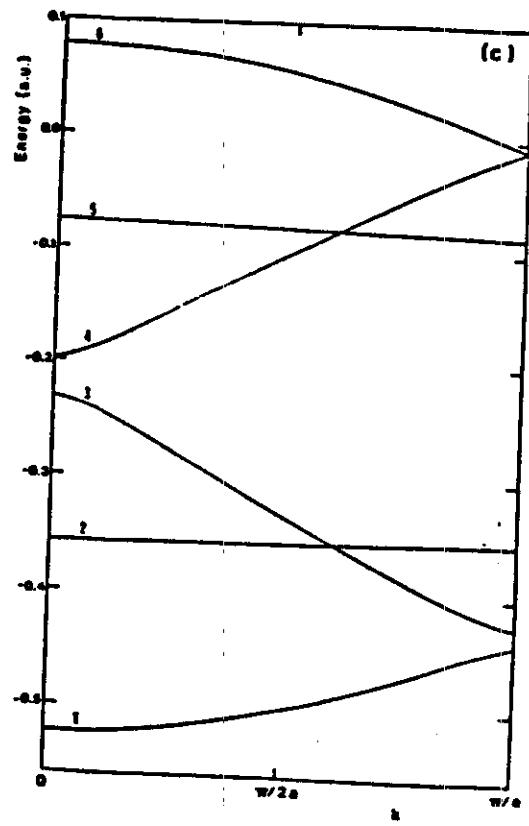
- Somewhat higher with H_2SO_4 (results not complete)
- $\sigma (\text{AsF}_5: \epsilon/\epsilon_0 \sim 10) > 10^3$ (Murase et al., Paper PI-51)

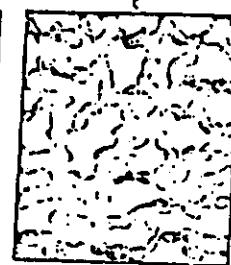
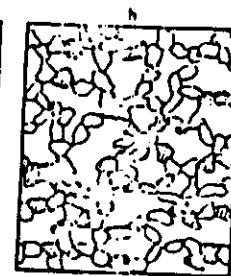
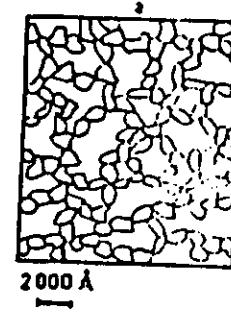
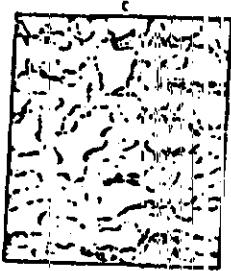
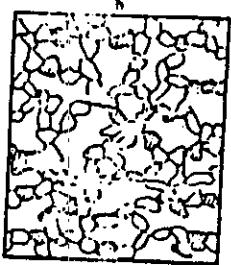
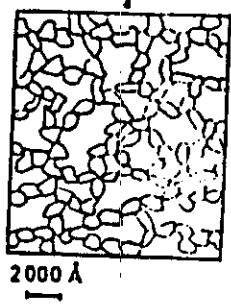
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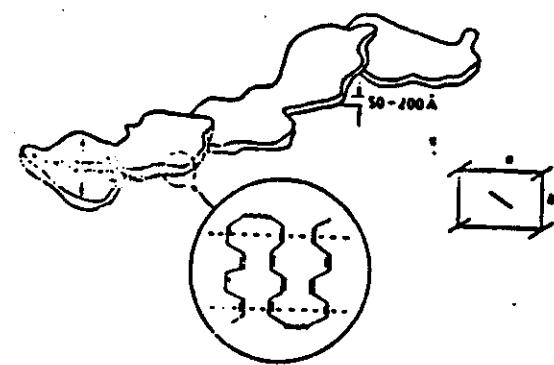
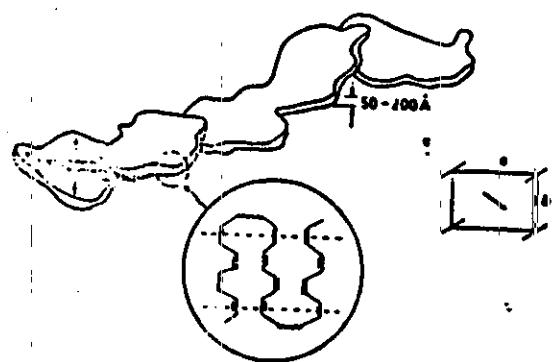


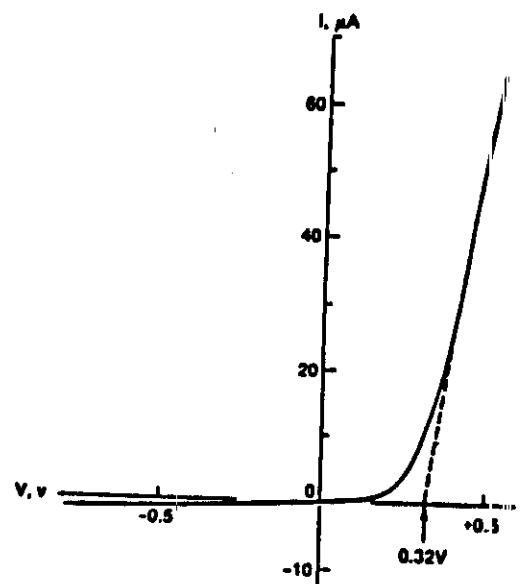




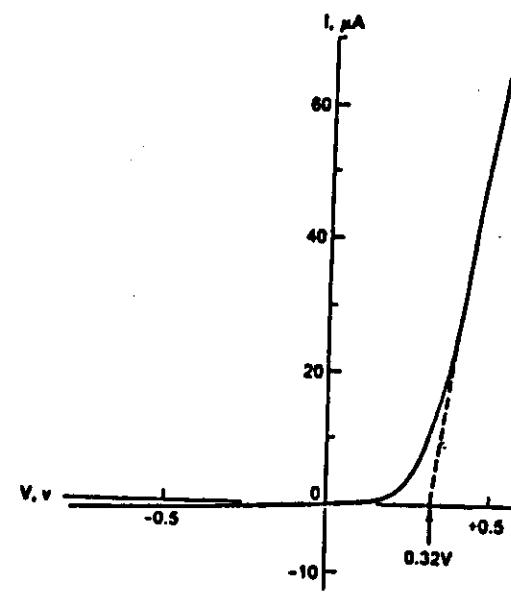








$I-V$ characteristic of a lightly doped $\text{CH}(\text{AsF}_5)_2:\text{In}$.



$I-V$ characteristic of a lightly doped $\text{CH}(\text{AsF}_5)_2:\text{In}$.

